NSN 5961-00-225-3412

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View Online at https://aerobasegroup.com/nsn/5961-00-225-3412 **Inclosure Material:** Metal **Overall Length:** Between 0.150 inches and 0.170 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.068 inches and 0.076 inches **End Application:** 1 wasp class lhd; austin ship class lpd-4 amphibious transport docks; ticonderoga class cg (47); kidd class ddg; spruance class dd (963); nimitz class cvn; tarawa class lha; forrestal class lha; arleigh burke class ddg; virginia class cgn (41) **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 breakdown voltage, dc **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 125.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Weapon system essential **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Test Data Document:** 24930-g390206 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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